NSN 5961-01-019-4974

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-019-4974 **Inclosure Material:** Plastic **Overall Length:** 0.380 inches **Overall Height:** 0.175 inches **Overall Width:** 0.350 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakover voltage, dc **Current Rating Per Characteristic:** 100.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig:

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